

MT53D512M32D2NP-046 AUT ES:D

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Contraction to the second seco	 MT53D512M32D2NP-046 AUT ES:D Micron Technology Inc. Integrated Circuits (ICs) Memory IC DRAM 16G 2133MHZ FBGA - For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MT53D512M32D2NP-046 AUT ES:D Specifications

Manufacturer Part Number	MT53D512M32D2NP-046 AUT ES:D
Manufacturer	Micron Technology Inc.
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	_
Memory Type	Volatile
Memory Format	DRAM
Technology	SDRAM - Mobile LPDDR4
Memory Size	16Gb (512M x 32)
Memory Interface	-
Clock Frequency	2133MHz
Write Cycle Time - Word, Page	-
Access Time	-
Voltage - Supply	1.1V
Operating Temperature	-40°C ~ 125°C (TC)
Mounting Type	_
Package / Case	-
Supplier Device Package	-
	Report errors?

MT53D512M32D2NP-046 AUT ES:D Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

MT53D512M32D2NP-046 AUT ES:D Payment Methods





If you have any question about MT53D512M32D2NP-046 AUT ES:D, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com